

# DUAL HIGH-SPEED DIFFERENTIAL LINE DRIVER

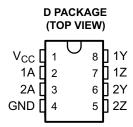
Check for Samples: uA9638C-EP

## **FEATURES**

- Meets or Exceeds ANSI Standard EIA/TIA-422-B
- **Operates From a Single 5-V Power Supply**
- Drives Loads as Low as 50  $\Omega$  up to 15 Mbps
- TTL- and CMOS-Input Compatibility
- **Output Short-Circuit Protection**
- **Interchangeable With National** Semiconductor™ DS9638

# SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- **Controlled Baseline**
- One Assembly/Test Site
- One Fabrication Site
- Rated From -40°C to 85°C
- **Extended Product Life Cycle**
- **Extended Product-Change Notification**
- **Product Traceability**



## **DESCRIPTION**

The uA9638C is a dual high-speed differential line driver designed to meet ANSI Standard EIA/TIA-422-B. The inputs are TTL and CMOS compatible and have input clamp diodes. Schottky-diode-clamped transistors are used to minimize propagation delay time. This device operates from a single 5-V power supply and is supplied in an 8-pin package.

The uA9638 provides the current needed to drive low-impedance loads at high speeds. Typically used with twisted-pair cabling and differential receiver(s), base-band data transmission can be accomplished up to and exceeding 15 Mbps in properly designed systems. The uA9637A dual line receiver is commonly used as the receiver. For even faster switching speeds in the same pin configuration, see the SN75ALS191.

The uA9638C is characterized for operation from -40°C to 85°C.



This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

1Z 2Y

Figure 2. Logic Diagram

Figure 1. Logic Symbol

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## ORDERING INFORMATION<sup>(1)</sup>

$T_A = T_J$	. •		ORDERABLE PART NUMBER	TOP-SIDE MARKING	VID NUMBER
–40°C to 85°C	SOIC - D Reel of 2500		UA9638CIDREP	96381	V62/12606-10XE

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

## **SCHEMATICS OF INPUTS AND OUTPUTS**

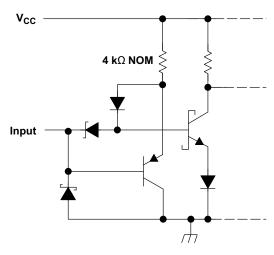


Figure 3. Equivalent of Each Input

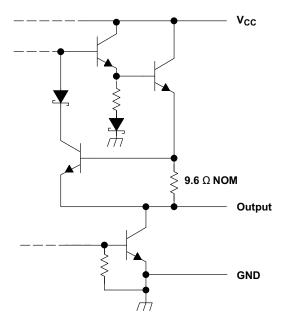


Figure 4. Typical of All Inputs

# **ABSOLUTE MAXIMUM RATINGS (1)**

over operating free-air temperature range (unless otherwise noted)

Over op	crating free all temperature range (unless otherwise noted)	
$V_{CC}$	Supply voltage range (2)	–0.5 V to 7 V
$V_{I}$	Input voltage range	–0.5 V to 7 V
	Continuous total power dissipation	See Dissipation Ratings Table
	Lead temperature 1,6 mm (1/16 inch) from 10 seconds	260°C
T <sub>A</sub>	Operating free-air temperature range	-40°C to 85°C
T <sub>stq</sub>	Storage temperature range	–65°C to 150°C

<sup>(1)</sup> Voltage values except differential output voltages are with respect to network GND.

<sup>(2)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



#### THERMAL INFORMATION

		uA9638C	
	THERMAL METRIC <sup>(1)</sup>	D	UNITS
		8 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance (2)	114.3	
$\theta_{JC}$	Junction-to-case thermal resistance	59.1	
$\theta_{JB}$	Junction-to-board thermal resistance (3)	55.3	°C/W
ΨЈТ	Junction-to-top characterization parameter <sup>(4)</sup>	12.7	
$\Psi_{JB}$	Junction-to-board characterization parameter (5)	54.7	

- For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- The junction-to-top characterization parameter,  $\psi_{JT}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining  $\theta_{JA}$ , using a procedure described in JESD51-2a (sections 6 and 7).
- The junction-to-board characterization parameter,  $\psi_{JB}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining  $\theta_{JA}$ , using a procedure described in JESD51-2a (sections 6 and 7).

## **DISSIPATION RATINGS**

PACKAGE	POWER RATING T <sub>A</sub> = 25°C (mW)	DERATING FACTOR  T <sub>A</sub> > 70°C  (mW/°C)	POWER RATING  T <sub>A</sub> = 85°C  (mW)
D	725	8.75	199

#### RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$V_{CC}$	Supply voltage	4.75	5	5.25	V
$V_{IH}$	High-level input voltage	2			V
$V_{IL}$	Low-level input voltage			0.8	V
I <sub>OH</sub>	High-level output current			-50	mA
I <sub>OL</sub>	Low-level output current			50	mA
T <sub>A</sub>	Operating free-air temperature	-40		85	°C

# **ELECTRICAL CHARACTERISTICS**

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.75 \text{ V}, I_1 =$	= −18 mA		-1	-1.2	V
		$V_{CC} = 4.75 \text{ V},$	I <sub>OH</sub> = −10 mA	2.5	3.5		
V <sub>OH</sub>	High level output voltage	$V_{IH} = 2 V,$ $V_{IL} = 0.8 V$	I <sub>OH</sub> = −40 mA	2			V
V <sub>OL</sub>	Low level output voltage	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V},$ $I_{OL} = 40 \text{ mA}$				0.5	V
V <sub>OD1</sub>	Magnitude of differential output voltage	V <sub>CC</sub> = 5.25 V, I <sub>O</sub> = 0 A			1.25 x V <sub>OD2</sub>		V
V <sub>OD2</sub>	Magnitude of differential output voltage	V <sub>CC</sub> = 4.75 V to See Figure 5	$5.25 \text{ V}, \text{ R}_{\text{L}} = 100 \Omega,$	2			٧
Δ V <sub>OD</sub>	Change in magnitude of differential output voltage (2)	V <sub>CC</sub> = 4.75 V to See Figure 5	$5.25 \text{ V}, \text{ R}_{\text{L}} = 100 \Omega,$			±0.4	V
V <sub>oc</sub>	Common-mode output voltage <sup>(3)</sup>	V <sub>CC</sub> = 4.75 V to See Figure 5	$5.25 \text{ V}, \text{ R}_{\text{L}} = 100 \Omega,$			3	V

- All typical values are at  $V_{CC}$  = 5 V and  $T_A$  = 25°C.  $\Delta |V_{OD}|$  and  $\Delta |V_{OC}|$  are the changes in magnitude of  $V_{OD}$  and  $V_{OC}$ , respectively, that occur when the input is changed from a high level
- In Standard EIA-422-A, V<sub>OC</sub>, which is the average of the two output voltages with respect to ground, is called output offset voltage, V<sub>OS</sub>.



# **ELECTRICAL CHARACTERISTICS (continued)**

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
$\Delta  V_{OC} $	Change in magnitude of common-mode output voltage (2)	V <sub>CC</sub> = 4.75 V to See Figure 5	5.25 V, $R_L = 100 \Omega$ ,			±0.4	٧
			V <sub>O</sub> = 6 V		0.1	100	
Io	Output current with power off	V <sub>CC</sub> = 0 V	V <sub>O</sub> = −0.25 V		-0.1	-100	μΑ
			$V_0 = -0.25 \text{ V to 6 V}$			±100	
I	Input current	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I}$	= 5.5 V			50	μΑ
I <sub>IH</sub>	High-level input current	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I}$	= 2.7 V			25	μΑ
I <sub>IL</sub>	Low-level input current	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I}$	= 0.5 V			-200	μΑ
I <sub>OS</sub>	Short-circuit output current <sup>(4)</sup>	$V_{CC} = 5.25 \text{ V}, V_{C}$	) = 0 V	-50		-150	mA
I <sub>CC</sub>	Supply current (both drivers)	V <sub>CC</sub> = 5.25 V, No	o load, All inputs at 0 V		45	65	mA

<sup>(4)</sup> Only one output at a time should be shorted, and duration of the short circuit should not exceed one second.

#### SWITCHING CHARACTERISTICS

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{d(OD)}$	Differential output delay time	$C_L = 15 \text{ pF}, R_L = 100 \Omega, \text{ See Figure 6}$		10		ns
$t_{t(OD)}$	Differential output transition time	$C_L = 15 \text{ pF}, R_L = 100 \Omega, \text{ See Figure 6}$		10		ns
t <sub>sk(o)</sub>	Output skew	See Figure 6		1		ns

## PARAMETER MEASUREMENT INFORMATION

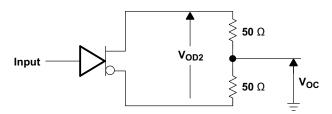
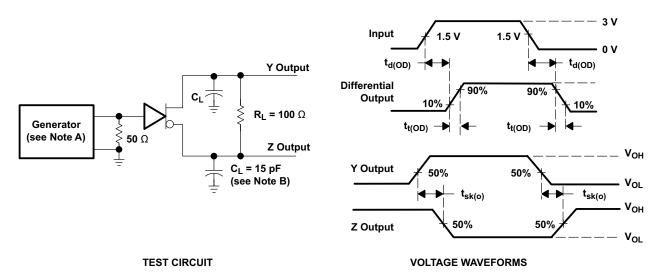


Figure 5. Differential and Common-Mode Output Voltages



- A. The input pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , PRR  $\leq 500$  kHz,  $t_w = 100$  ns,  $t_r = \leq 5$  ns.
- B. C<sub>L</sub> includes probe and jig capacitance.

Figure 6. Test Circuit and Voltage Waveforms



# PACKAGE OPTION ADDENDUM

10-Dec-2020

#### **PACKAGING INFORMATION**

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
UA9638CIDREP	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	96381	Samples
V62/12606-01XE	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	96381	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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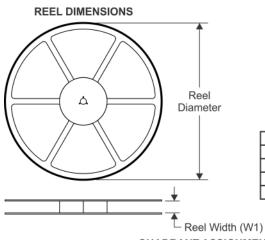


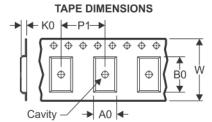


10-Dec-2020

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# TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
ı		Dimension designed to accommodate the component length
ı	K0	Dimension designed to accommodate the component thickness
ı	W	Overall width of the carrier tape
-	P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA9638CIDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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#### \*All dimensions are nominal

ĺ	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
	UA9638CIDREP	SOIC	D	8	2500	340.5	336.1	25.0	

# **PACKAGE OUTLINE**

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



## NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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